TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX245F,TC74LCX245FW,TC74LCX245FT,TC74LCX245FK

Low-Voltage Octal Bus Transceiver with 5-V Tolerant Inputs and Outputs

The TC74LCX245F/FW/FT/FK is a high-performance CMOS octal bus transceiver. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

The direction of data transmission is determined by the level of the DIR input. The enable input (\overline{OE}) can be used to disable the device so that the busses are effectively isolated.

All inputs are equipped with protection circuits against static discharge.

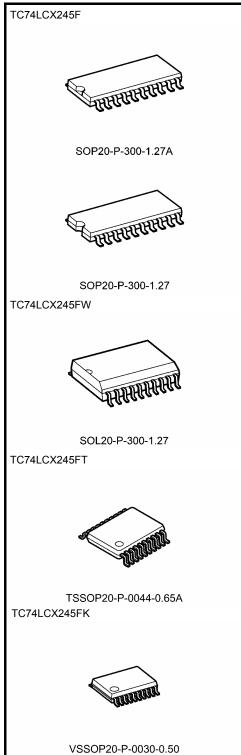
Features (Note)

- Low-voltage operation: $V_{CC} = 2.0$ to 3.6 V
- High-speed operation: $t_{pd} = 7.0 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Ouput current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min) (V}_{CC} = 3.0 \text{ V)}$
- Latch-up performance: ±500 mA
- Available in JEDEC SOP, JEITA SOP and TSSOP
- Bidirectional interface between 5.0 V and 3.3 V signals
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 245 type

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

All floating (high impedance) bus pins must have their input levels fixed by means of pull-up or pull-down resistors.

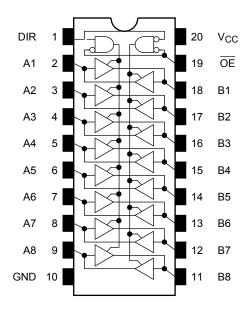
Note: xxxFW (JEDEC SOP) is not available in Japan.



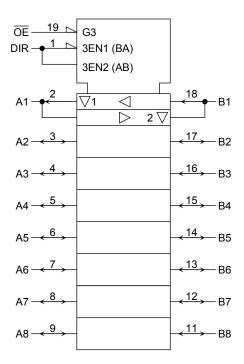
Weight

SOP20-P-300-1.27A : 0.22g (typ.) SOP20-P-300-1.27 : 0.22g (typ.) SOL20-P-300-1.27 : 0.46 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Inputs		Outputa	Function			
ŌĒ	DIR	Outputs	A-Bus	B-Bus		
L	L	A = B	Output	Input		
L	Н	B = A	Input	Output		
Н	Х	Z	Z			

X: Don't care

Z: High impedance



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	−0.5 to 7.0	V
DC input voltage (DIR, $\overline{\text{OE}}$)	V _{IN}	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC bus I/O voltage	V _{I/O}	-0.5 to V _{CC} + 0.5	V
		(Note 3)	
Input diode current	I _{IK}	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Range (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	2.0 to 3.6	V	
Tower supply voltage	VCC	1.5 to 3.6 (Note 2)		
Input voltage (DIR, \overline{OE})	V _{IN}	0 to 5.5	٧	
Bus I/O voltage	Viva	0 to 5.5 (Note 3)	V	
Bus I/O voltage	V _{I/O}	0 to V _{CC} (Note 4)	V	
Output current	I _{OH} /I _{OI}	±24 (Note 5)	mA	
Output current	IOH/IOL	±12 (Note 6)	IIIA	
Operating temperature T _{opr}		-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V	

Note 1: The operating range is required to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either VCC or GND. Please connect both bus inputs and the bus outputs with VCC or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.

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Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 6: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 7: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V



Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
	H-level	V _{IH}	-	_	2.7 to 3.6	2.0	_	
Input voltage	L-level	V _{IL}	-	_	2.7 to 3.6		0.8	V
				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	_	
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -12 mA	2.7	2.2	_	
				I _{OH} = -18 mA	3.0	2.4	_	
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	V
			V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.7 to 3.6	_	0.2	
	L-level	\/		I _{OL} = 12 mA	2.7	_	0.4	
	L-level	L-level V _{OL}		I _{OL} = 16 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage current		I _{IN}	V _{IN} = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μА
3-state output OFF state current		I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		2.7 to 3.6	_	±5.0	μА
Power-off leakage current		l _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0	_	10.0	μΑ
Quiescent supply current			V _{IN} = V _{CC} or GND		2.7 to 3.6		10.0	
		icc	$V_{IN}/V_{OUT} = 3.6 \text{ to } 5.5 \text{ V}$		2.7 to 3.6	_	±10.0	μА
Increase in I _{CC} per input		Δl _{CC}	V _{IH} = V _{CC} - 0.6 V		2.7 to 3.6		500	

AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	8.0	ns
Tropagation delay time	t_{pHL}	rigure 1, rigure 2	3.3 ± 0.3	1.5	7.0	
Output enable time	t_{pZL}	Figure 4 Figure 2	2.7	_	9.5	ns
Output enable time	t _{pZH}	Figure 1, Figure 3	3.3 ± 0.3	1.5	8.5	
Output disable time	t_{pLZ}	Figure 1, Figure 3	2.7	_	8.5	ns
Output disable time	t_{pHZ}	r igure 1, r igure 3	3.3 ± 0.3	1.5	7.5	115
Output to output skew	t _{osLH}	(1)	2.7	_	_	ns
Output to output skew	t _{osHL}	(Note)	3.3 ± 0.3	_	1.0	115

Note: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$



Dynamic Switching Characteristics (Ta = 25°C, input: t_r = t_f = 2.5 ns, C_L = 50 pF, R_L = 500 Ω)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

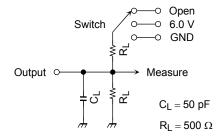
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	DIR, OE	3.3	7	pF
Bus input capacitance	C _{I/O}	An, Bn	3.3	8	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$ (Not	9) 3.3	25	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$

AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t_{pLZ} , t_{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND

Figure 1

AC Waveform

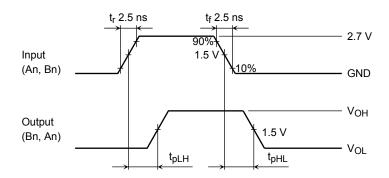


Figure 2 tpLH, tpHL

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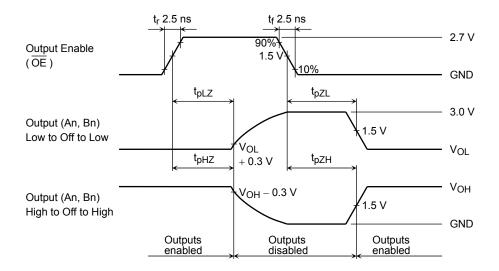
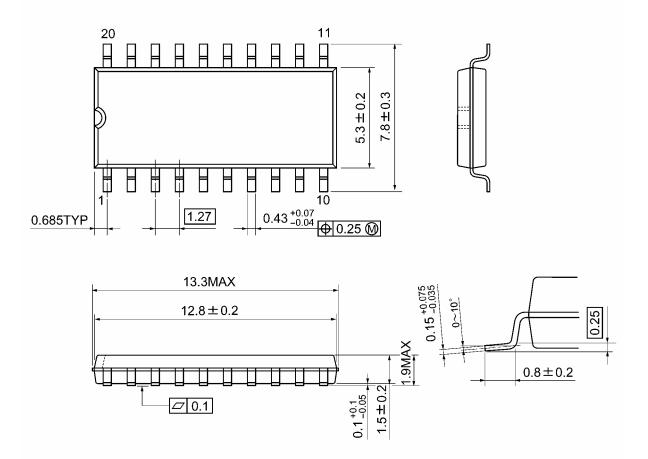


Figure 3 $t_{\text{pLZ}},\,t_{\text{pHZ}},\,t_{\text{pZL}},\,t_{\text{pZH}}$

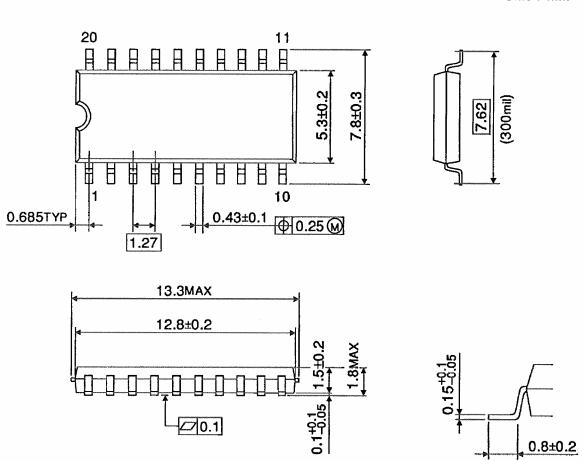
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SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

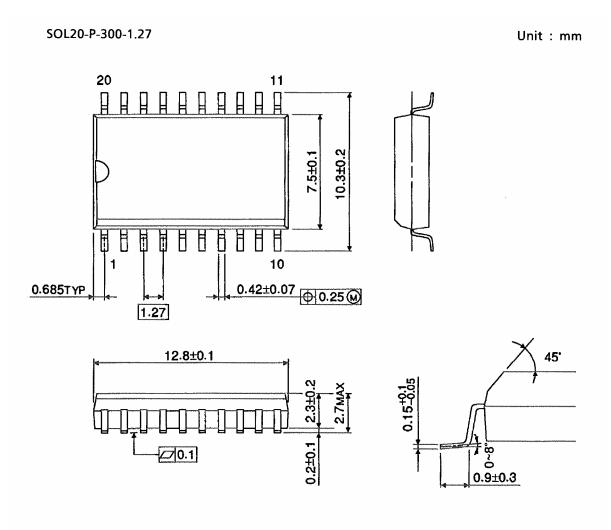
SOP20-P-300-1.27 Unit: mm



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Weight: 0.22 g (typ.)

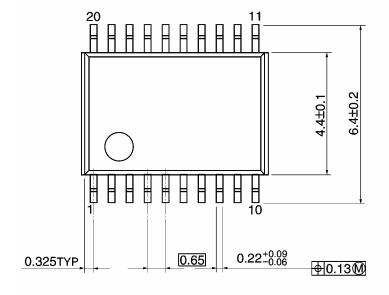
Package Dimensions (Note)

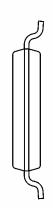


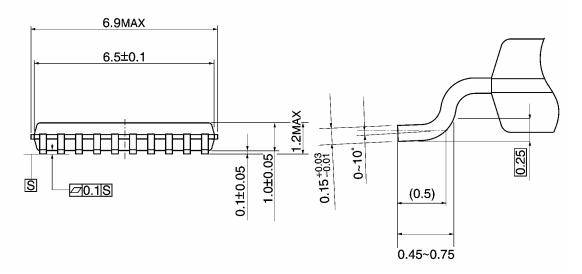
Note This package is not available in Japan.

Weight: 0.46 g (typ.)

TSSOP20-P-0044-0.65A Unit: mm

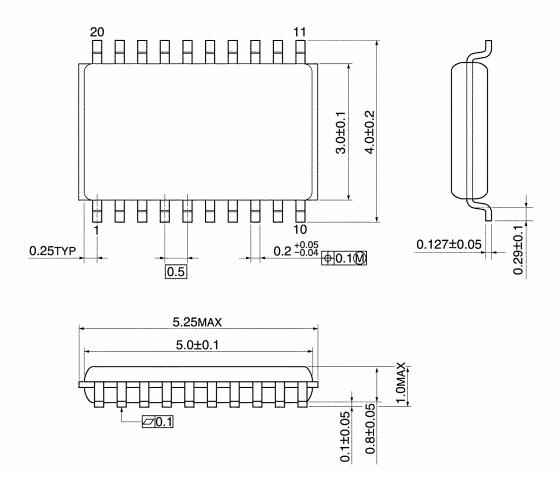






Weight: 0.08 g (typ.)

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)

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